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# M56710FP

## F2F Magnetic Stripe Encoding Card Reader

REJ03F0175-0201 Rev.2.01 Mar 31, 2008

#### **Description**

The M56710FP is a semiconductor integrated circuit of Bi-CMOS structure having an F2F demodulator function for magnetic card reader.

#### **Features**

- Low current dissipation (0.7 mA when on standby as a standard)
- Provided with glance-over selection input (4, 8, and 16 bits)
- Provided with output polarity ("L" active or "H" active) switching input
- Miniature mini-mold package
- Wide operating temperature range Ta = -20 to  $75^{\circ}C$

#### **Application**

Magnetic card reader

## **Functional Description**

Data signal which is read from magnetic card via magnetic head is input from HD2 and HD1 pins., and converted into F2F pattern signal by analog processing in amplifier OP1, differentiator OP2, sensitivity setting circuit and waveform shaping circuit. If F2F signal is input, the logic section glances over the prescribed number of bits set by IB1 and IB2 input before performing digital processing, and then outputs card reading signal CLS, read clock signal RCP, and read data signal RDT. INV turning to "L" switches each output of CLS. RCP and RDT from "L" active to "H" active.

#### • Standard Bits:

Let the number of glance-over bits set by IB1 and IB2 be M.

Let the Mth FC (flux change) through M+1st FC after LDI input is turned from "L" to "H" be a standard bit with a time width of TB0.

I/O is discriminated from the next bit to this standard bit as a data bit.

• I/O discrimination

Let the data bit time width of a data bit be TBn, and if there is one next FC between the FC at the end of that bit (i.e. the beginning of the next bit) to 5/7TBn, let the next bit (Bn+1) be data "1", and, if there is no FC, be data "0".

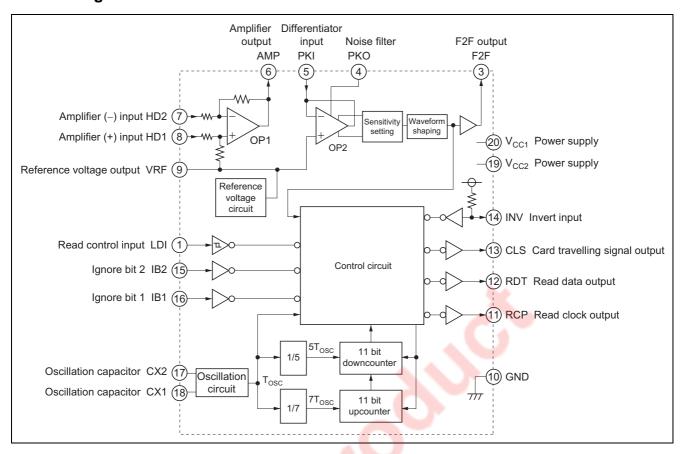
• Output signal time width

When letting the oscillation cycle of oscillation circuit be  $T_{OSC}$ .

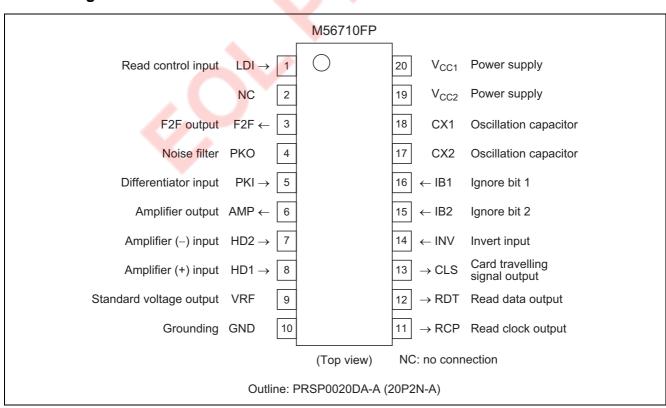
- RCP output pulse width TOW: about 16 T<sub>OSC</sub>
- RCP delay time to RDT: about 8 T<sub>OSC</sub>



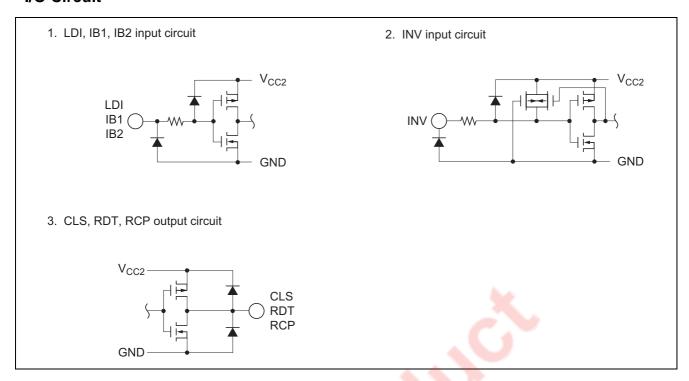
### **Block Diagram**



### **Pin Arrangement**



## I/O Circuit



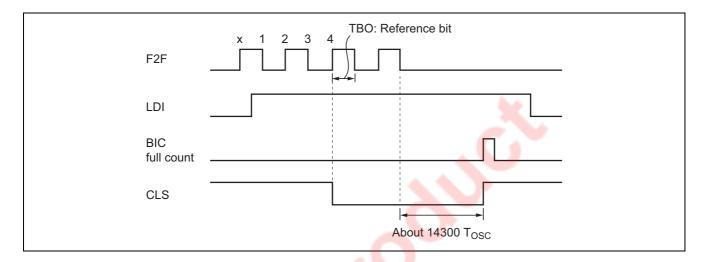
# **Pin Function Description**

Pin	Pin		
No.	Name	Name	Function
1	LDI	Read control input	Schmidt trigger input. At "L", reset the internal digital circuit. At "H",
			F2F modulation is possible.
3	F2F	F2F output	F2F signal output that has amplified, differentiated and further
			waveform-shaped the magnetic head signal.
4	PKO	Noise filter	Connect noise removing capacitor CNF between PKI and PKO.
5	PKI	Differentiator input	Refer to PKO and AMP.
6	AMP	Amplifier output	Connect resistor RPK and capacitor CPK between AMP and PKI.
7	HD2	Amplifier (–) input	Connect magnetic head between HD1 and HD2.
8	HD1	Amplifier (+) input	Connect magnetic head between HD1 and HD2.
9	VRF	Reference voltage output	Reference voltage output of V <sub>CC</sub> 1/2
10	GND	Grounding	
11	RCP	Read clock output	Clock pulse output after F2F modulation
12	RDT	Read data output	Data output after F2F modulation
13	CLS	Card travelling signal output	Signal output indicating that card is travelling
14	INV	Invert input	CLS, RDT and RCP output becomes "L" active at "H" (OPEN), and "H"
			active at "L".
15	IB2	Ignore bit 2	Glance-over bit setting pin
16	IB1	Ignore bit 1	Glance-over bit setting pin
17	CX2	Oscillation capacitor	Connect capacitor C <sub>OSC</sub> between CX1 and CX2 to set oscillation
			frequency.
18	CX1	Oscillation capacitor	Connect capacitor Cosc between CX1 and CX2 to set oscillation
			frequency.
19	V <sub>CC2</sub>	Power supply	Digital circuit section power supply pin. Supply voltage is V <sub>CC</sub> .
20	V <sub>CC1</sub>	Power supply	Analog circuit section power supply pin. Supply voltage is Vcc (same
			voltage as V <sub>CC2</sub> ).

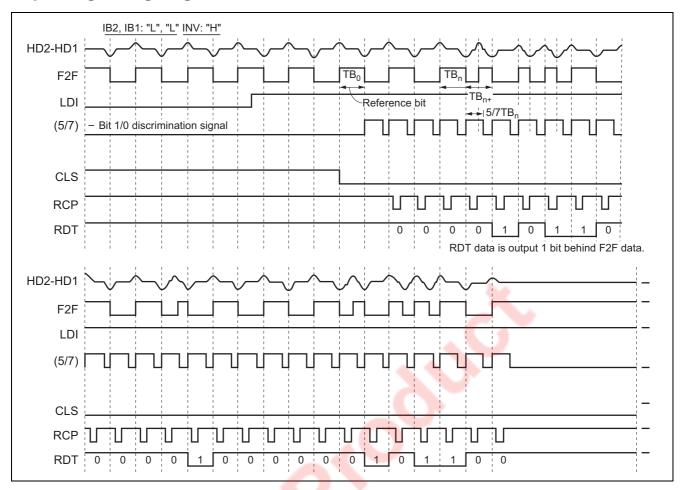
# Glance-Over Bit Setting and Timing By IB1 and IB2

IB2 input	IB1 input	Number of glance- over bits	Description
L	L	4	Internal digital circuit is reset with LDI input at "L".
L	Н	8	LDI input may be at "H" at all times.
Н	L	16	CLS output turns to "L" after counting the flux change FC (change in the status of F2F) of the number of glance-over bits, and returns to "H" when BIC (bit interval counter) has fully counted. (At "L" active).
Н	Н	_	_

Note: IB2, IB1 : "L", "L"



## **Operating Timing Diagram**



### **Absolute Maximum Ratings**

 $(Ta = -20 \text{ to } 75^{\circ}\text{C}, \text{ unless otherwise noted})$ 

Item	Symbol	Ratings	Unit	Conditions
Supply voltage	V <sub>CC</sub>	-0.3 to +6.5	V	V <sub>CC1</sub> , V <sub>CC2</sub>
Input voltage	VI	$-0.3$ to $V_{\text{CC}}$ +0.3	V	LDI, IB1, IB2, INV
Input voltage	VI	$-0.3$ to $V_{\text{CC}}$ +0.3	V	HD1, HD2
Output voltage	lo	-10 to +10	mA	CLS, RDT, RCP
Differential input voltage	$V_{ID}$	-1.2 to +1.2	V	Between HD2 and HD1 pins
Operating temperature	Topr	-20 to 75	°C	
Storage temperature	Tstg	-55 to 125	°C	

Notes: 1. Voltage is based on GND pin of the circuit (0 V), unless otherwise noted.

2. Direction of the current flowing into the circuit is represented by "positive" (without code) and that flowing out of the circuit by "negative" (–code).

# **Recommended Operating Conditions**

 $(Ta = -20 \text{ to } 75^{\circ}\text{C}, \text{ unless otherwise noted})$ 

Item				Limits			
		Symbol	Min Typ		Max	Unit	Test Conditions
Supply voltage	V <sub>CC1</sub> , V <sub>CC2</sub>	V <sub>CC</sub>	4.0	5	5.5	V	V <sub>CC1</sub> and V <sub>CC2</sub> shall have the identical voltage.
Input voltage	LDI	Vı	0		Vcc	V	
"H" input voltage	IB1, IB2, INV	V <sub>IH</sub>	0.8V <sub>CC</sub>		Vcc	V	
"L" input voltage	IB1, IB2, INV	V <sub>IL</sub>	0		0.2V <sub>CC</sub>	V	
"H" output current	CLS, RDT, RCP	Іон	-0.5	_	0	mA	
"L" output current	CLS, RDT, RCP	l <sub>OL</sub>	0	_	5	mA	
Differential input voltage	HD2-HD1	V <sub>IN</sub>	3	_	80	mVp-p	
Input frequency	HD2-HD1	f <sub>IN</sub>	0.3		15	kHz	
Oscillation frequency		fosc	0.2	_	2	MHz	fosc = 1/Tosc
External capacitor	CX1, CX2	Cosc	25	_	100	pF	fosc ∞ 1/Cosc
External capacitor	CX1, CX2	Cosc	_	33	_	pF	Reference value when corresponding to 210BPI
External resistor	AMP	R <sub>PK</sub>	_	470	3	Ω	Reference value when corresponding to 210BPI
External capacitor	PKI	Срк	_	0.033		μF	Reference value when corresponding to 210BPI
External capacitor	PKI, PKO	C <sub>NF</sub>	_	220	<del></del>	pF	Reference value
External resistor	PKI, F2F	R <sub>PF</sub>		4.7	_	ΜΩ	Reference value
External capacitor	V <sub>CC1</sub> , V <sub>CC2</sub>	C <sub>VC</sub>	-	0.1	_	μF	Reference value
External capacitor	VRF	$C_{VR}$	0.8	1	2	μF	Reference value

## **Electrical Characteristics**

 $(Ta = -20 \text{ to } 75^{\circ}\text{C}, V_{CC} = 5 \text{ V}, \text{ unless otherwise noted})$ 

			Test		Limits			
Itor	_	Cumbal	Circ	N/I:	T	May	l lmit	Toot Conditions
Threshold	n IB1, IB2,	Symbol VTH	uit	Min 0.3V <sub>CC</sub>	Тур	Max 0.7V <sub>CC</sub>	Unit V	Test Conditions V <sub>CC</sub> = 4 to 5.5 V
voltage	INV	VIII	_	0.3VCC	_	0.7 VCC	V	VCC = 4 to 5.5 V
"L" output	CLS, RDT,	V <sub>OL</sub>	2		_	0.2	V	V <sub>CC</sub> = 4 V
voltage	RCP	102	2	_	_	0.4	V	$I_{OL} = 5 \text{ mA}$
"H" output	CLS, RDT,	V <sub>OH</sub>	2	3.8	_	_	V	$V_{CC} = 4 \text{ V}$ $I_{OH} = -10  \mu\text{A}$
voltage	RCP		2	3.2	_	_	V	$I_{OH} = -0.5 \text{ mA}$
"L" input current	LDI, IB1, IB2	IIL	2	-10	_	+10	μΑ	$V_{CC} = 5.5 \text{ V}, V_I = 0 \text{ V}$
"L" input current	INV	IIL	2	-80	_	-10	mA	$V_{CC} = 5.5 \text{ V}, V_I = 0 \text{ V}$
"H" input current	LDI, IB1, IB2, INV	IIH	2	-10	_	+10	μА	$V_{CC} = 5.5 \text{ V}, V_I = 5.5 \text{ V}$
Positive	INV	IIT+	2	-250	_	-50	μА	$V_{CC} = 5.5 \text{ V}, V_I = VTH$
threshold								
current							<b>C</b> 4	
Reference voltage	VRF	VREF	1	2.3	2.5	2.7	V	$V_{IN} = 0 \text{ mVp-p}$
Voltage gain 1	OP1	GV11	3	18	20	24	Double	f <sub>IN</sub> = 1 kHz
	004	0) (0.4		40		0.4	5	V <sub>IN</sub> = 80 mVp-p sine wave
Voltage gain 2	OP1	GV21	3	18	20	24	Double	$f_{IN} = 15 \text{ kHz}$
Input	OP1	RIN1	3	7	10	14	kΩ	$V_{IN} = 80 \text{ mVp-p sine wave}$ $f_{IN} = 1 \text{ kHz}$
Input resistance	OPT	KIINT	3		10	14	KS 2	$V_{IN} = 80 \text{ mVp-p sine wave}$
Maximum	OP1	VOPP1	3	2	<b>\</b> _		Vp-p	f <sub>IN</sub> = 1 kHz sine wave
output voltage		10111					1 1 1	THD AMP = 5%
"L" sensitivity	PKI – F2F	IIL2	4		_	-0.3	μА	VM, F2F < 0.5 V
current		4					-	
"H" sensitivity current	PKI – F2F	IIH2	4	0.3	_	_	μА	VM, F2F > 4.5 V
Positive	PKI – F2F	VTH+2	5	0.2	0.45	0.7	V	On the VRF basis
threshold								
voltage	510 55	) (THE )					.,	0 11 1/0=1
Negative threshold voltage	PKI – F2F	VTH-2	5	-0.7	-0.45	-0.2	V	On the VRF basis
Threshold differential	PKI – F2F	VTHD2	_	-0.15	_	0.15	V	(VTH+2) -  VTH-2
voltage								
Pin voltage	PKO	VPKO	4	-1.2	_	1.2	V	On the VRF basis
range								PK   = 1 mA – +1 mA
"L" output voltage	F2F	VOL3	5	_	_	0.5	V	VPKI = 0 V, IF2F = 0.5 mA
"H" output	F2F	VOH3	5	4.5	_	_	V	VPKI = 5 V, IF2F = -0.5 mA
Positive threshold voltage	LDI	VTH+4	6	2.5	_	3.5	V	

			Test		Limits			
Item		Symbol	Circ uit	Min	Тур	Max	Unit	Test Conditions
Negative threshold voltage	LDI	VTH-4	6	1.5	_	2.7	V	
Hysterisis width	LDI	VHY4		0.5	_	1.5	V	(VTH+4) – (VTH-4)
Standby circuit current	V <sub>CC1</sub> , V <sub>CC2</sub>	ICCW	1		0.7	1.0	mA	V <sub>IN</sub> = 0 mVp-p
Operating circuit current	V <sub>CC1</sub> , V <sub>CC2</sub>	ICCR	1		1.9	2.4	mA	$\begin{split} f_{\text{IN}} &= 8.2 \text{ kHz} \\ V_{\text{IN}} &= 68 \text{ mVp-p sine wave} \\ f_{\text{OSC}} &= 1 \text{ MHz} \end{split}$
Oscillation frequency	RCP	f <sub>OSC</sub>	1	0.75	_	1.5	MHz	C <sub>OSC</sub> = 33 pF
Output pulse width	RCP	TOW	7	15	16	17	μ\$	f <sub>OSC</sub> = 1 MHz
Intra-output delay time	RDT, RCP	TOD	7	7	8	9	μS	f <sub>OSC</sub> = 1 MHz
Input noise width	INV	TNW	7	0.5	_	_	μS	

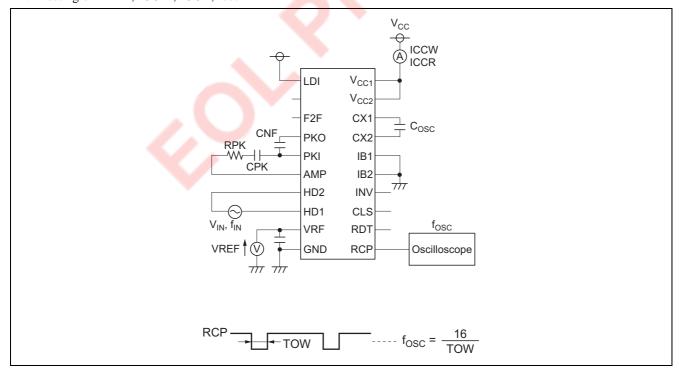
Note: 1. Min. and max. limits do not represent absolute values.

2. Typ. limits represent standard values when  $Ta = 25^{\circ}C$  and  $V_{CC} = 5V$ .

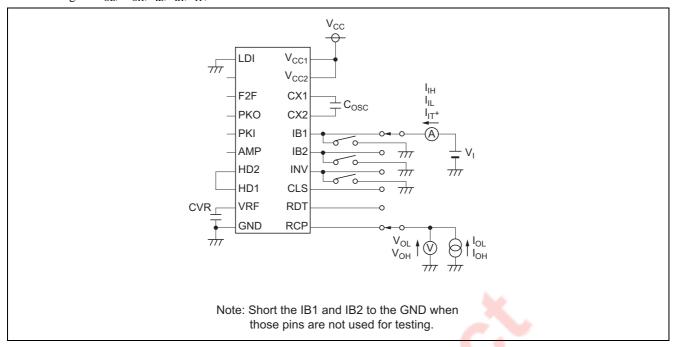
### **Test Circuit**

On the following drawing,  $C_{OSC} = 33 \text{ pF}$ ,  $RPK = 470 \Omega$ ,  $CPK = 0.033 \mu F$ , CNF = 470 pF,  $CVR = 1 \mu F$ 

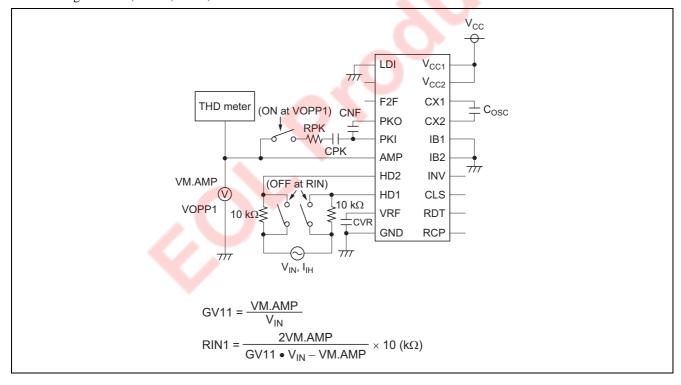
1. Testing of VREF, ICCW, ICCR, fosc



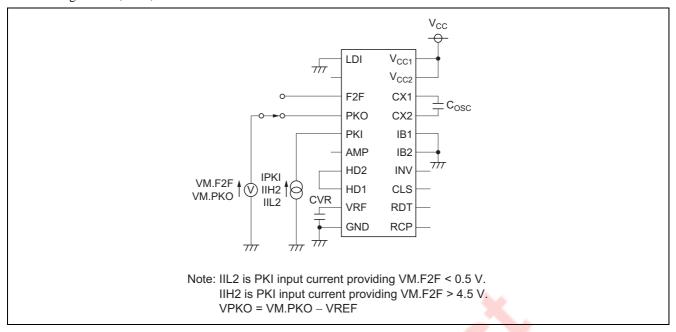
#### 2. Testing of $V_{OL}$ , $V_{OH}$ , $I_{IL}$ , $I_{IH}$ , $I_{IT+}$



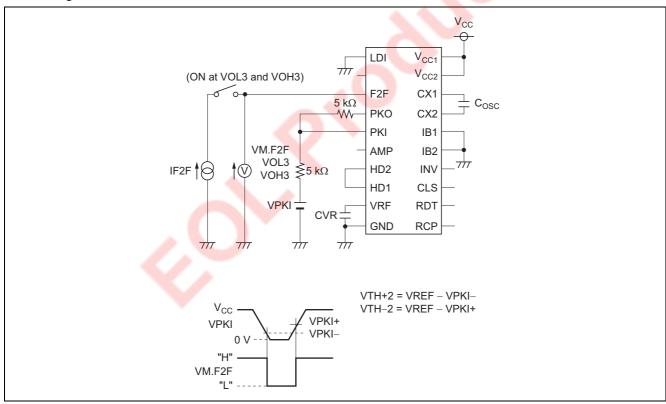
### 3. Testing of GV11, GV21, RIN1, VOPP1



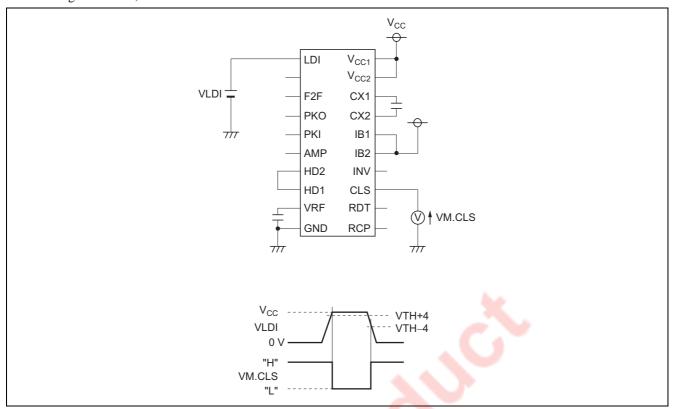
#### 4. Testing of IIH2, IIL2, VPKO



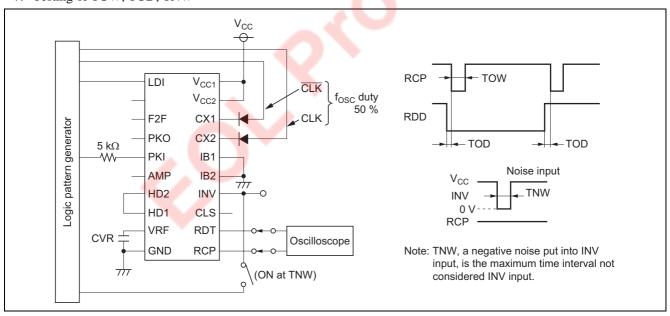
#### 5. Testing of VTH+2, VTH-2, VOL3, VOH3



#### 6. Testing of VTH+4, VTH-4

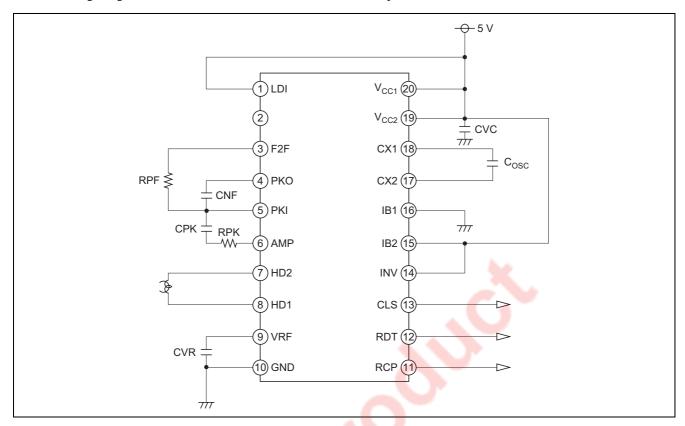


## 7. Testing of TOW, TOD, TNW

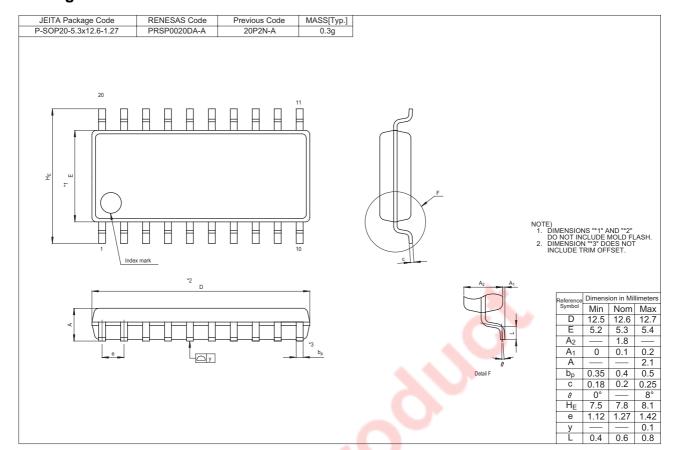


## **Application Example**

When setting the glance-over bit to 16 bits to let it be "L" active output



## **Package Dimensions**



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